

## The growth of the silver nanoparticles on the mesoporous silicon and macroporous silicon: A comparative study

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Two porous silicon (PS) layers, namely mesoPS and macroPS have been prepared by electrochemical etching (ECE) and photo–electrochemical etching (PECE) processes, respectively. The surface morphology of mesoPS and macroPS reflects a different form of morphology. Silver nanoparticles (AgNPs) have been obtained through immersion of PS samples in AgNO<sub>3</sub> solution. The mechanism of Ag growth depends on the substrate morphology. In the case of using mesoPS substrate, the AgNPs have sizes ranging from 0.25 to 2.25 μm, so they can't enter inside pores and therefore they aggregate on the mesoPS surface, while by using macroPS substrate, they have sizes ranging from 0.1 to 1.5 μm, decorate the inner of the pores and the separate Ag nanoaggregates form on the macroPS surface. The highest SERS has been obtained for AgNPs/macroPS substrate rather than AgNPs/mesoPS substrate. The enhancement factor (EF) values achieved by using AgNPs deposited on macroPS and mesoPS substrates are about (1.8×10<sup>6</sup>) and (3.2×10<sup>4</sup>), respectively.

**Keywords:** Porous silicon, Silver nanoparticles, Immersion plating, SERS

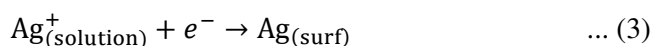
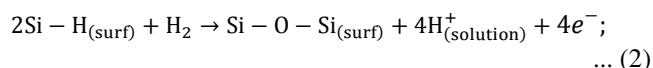
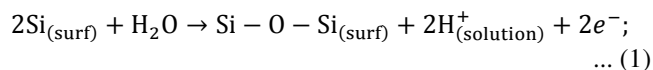
### 1 Introduction

Porous silicon (PS) has attracted much attention since the finding of its visible photoluminescence (PL) at room temperature<sup>1</sup>. Recently, it has been shown that PS can reduce positive metal ions since it acts as a modest reducing agent, therefore the nanoparticles of these metals can be spontaneously formed onto PS yielding surface enhanced Raman scattering (SERS)–active substrate<sup>2-5</sup>.

PS can exhibit different morphologies and typical pore sizes, therefore it is characterized by its porosity (volumetric fraction of void within PS), its thickness, its internal surface (taking into account the pore surfaces), and its morphology (shape and pore size)<sup>6</sup>. The PS structures are categorized to the dominant pore diameter (*d*) as microPS (*d* ≤ 2 nm), mesoPS (2 nm < *d* < 50 nm) and macroPS (*d* > 50 nm)<sup>6,7</sup>. The resulting pore features of PS are strongly dependent on the doping type and orientation of the silicon (Si) substrate and the ECE factors<sup>3,8-10</sup>.

The physicochemical properties of the AgNPs, such as the surface plasmon resonance and big effective scattering cross section of individual AgNPs make them perfect nominees for molecular

labeling, where phenomena such as SERS can be subjugated<sup>3,11,12</sup>, therefore the synthesis of Ag nanostructures has been an active research area because of their excellent optical properties, which strongly depend on size, shape and composition. A variety of methods has been used to synthesize the AgNPs for instance, sonochemical synthesis, laser ablation, electrochemical way, thermal decomposition, and microwave irradiation<sup>3,4,13,14</sup>. However, practically all these methods are costly and require special technique. PS has a very large hydrogenated internal surface area<sup>15,16</sup>, which plays an essential role in the deposition process of Ag on the PS layer by an efficient and simple method called an immersion plating<sup>3,5</sup>. Immersion of PS into silver nitrates (AgNO<sub>3</sub>) solution performs an involuntary composition of AgNPs by way of Ag ions reduction through Si–H bonds on the surface of the PS sample, as shown in the following equations<sup>3</sup>:



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The sensitivity of SERS strongly depends on the formation of electromagnetic "hotspots" sites, where the local electric field is very intense. Hence, at these sites, the Raman signals from molecules of the analyte are particularly strong and contribute to the main fraction of the overall Raman intensity<sup>17</sup>.

In this work, the effects of the PS types (*p*-type mesoPS (mesoPS) and *n*-type macroPS (macroPS)) on the growth mechanism of the AgNPs and corresponding SERS have been studied based on the analysis of the field emission scanning electron microscope (FE-SEM) images, X-ray diffraction pattern (XRD) and SERS.

## 2 Experimental Details

### 2.1 Chemical materials

Hydrofluoric acid (HF) of 48% concentration, ((CDH), India) was diluted with high purity ethanol (C<sub>2</sub>H<sub>5</sub>OH) of 99.9% concentration (Sigma-Aldrich, Germany) in order to prepare a required etching solution with a concentration of about 29% HF. AgNO<sub>3</sub> (Aldrich, 99.99%) was dissolved in triply distilled water for preparing a required AgNO<sub>3</sub> solution with a concentration of about (0.01 M) by using the following equation<sup>18</sup>:

$$\text{Molarity} = \frac{W}{\frac{M.Wt}{V}} \quad \dots (4)$$

where, *W* (g) is the weight of the AgNO<sub>3</sub>, *M.Wt* (g/mole) is the molecular weight, and *V* (l) is the volume of the dissolved solution.

### 2.2 Preparation of PS samples

In this study, *p*-type (100) Si wafer and *n*-type (100) Si wafer with a resistivity of 10 Ω.cm were used as substrates for preparing mesoPS and macroPS, respectively. The dimensions of samples were 1.5×1.5 cm<sup>2</sup> exposed to the electrolyte which consisted of HF and absolute ethanol. The PS samples were prepared with a fixed etching current density of 14 mA/cm<sup>2</sup> and a fixed etching time of 25 min by ECE of *p*-type wafer and PECE of *n*-type wafer. A laser source with intensity of 30 mW/cm<sup>2</sup> and wavelength of 532 nm was used to illuminate *n*-type Si wafer. The etching process was performed at room temperature in a solution composed of a mixture (HF:C<sub>2</sub>H<sub>5</sub>OH=3:2). Si wafer acted as the anode electrode, while platinum (Pt) ring was used as the cathode electrode (Fig. 1). Prior to etching process, the samples were first

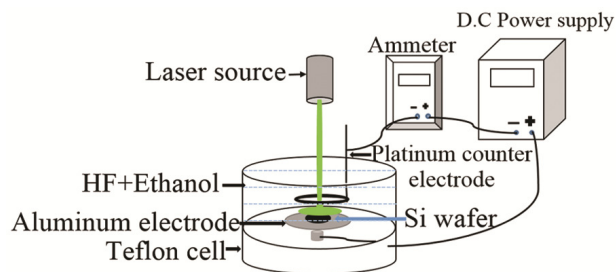


Fig. 1 — Schematic diagram of etching system with laser source and without laser source for PECE and ECE, respectively.

cleaned in a mixture of (HF:C<sub>2</sub>H<sub>5</sub>OH=1:10) for 10 min to remove the native oxide layer on the surface of the Si and then washed with high purity ethanol.

### 2.3 Fabrication of AgNPs on PS layer

The AgNPs were prepared at room temperature by immersion plating process. The fresh PS samples were immersed in the 0.01 M aqueous solution of AgNO<sub>3</sub> for 16 min to prepare sandwich structures of AgNPs/mesoPS and AgNPs/macroPS.

These structures were rinsed out in the HCl solution with a concentration of 0.01 M for 10 s in order to remove the contaminants adsorbed on the surfaces of AgNPs/PS substrates, and then the AgNPs/PS samples were incubated for 15 min in solution of R6G dye, which was used as analyte in this study. The specific weight of the dye was dissolved in ethanol to prepare the solutions of R6G dye with fixed concentration dye of 10<sup>-6</sup> M by using Eq. (4), where the molecular weight of R6G dye is about 479.02 g/mol.

### 2.4 Characterizations

The crystal structure of mesoPS, macroPS, AgNPs/mesoPS and AgNPs/macroPS samples was tested by the experiments of XRD (XRD – 6000, Shemadzue). A power diffraction system with CuK<sub>α</sub> X-ray tube (λ=0.154056 nm) was used. The morphology of some samples was examined by the FE-SEM (FE-SEM; MIRA3 TESCAN). The PL of the mesoPS and macroPS samples was examined by (PL; Cary Eclipse FL 0912M014) at room temperature using excitation laser wavelength of 325 nm. Raman spectra of R6G dye were measured with the dispersive Raman microscope (Almega Thermos Nicolet) using 532 nm of a Nd:YLF laser for excitation, the laser power was 30 mW. For each spectrum, the integration time was set as 2 s.

### 3 Results and Discussion

#### 3.1 Morphological features of the fresh PS

The porosity, the porous layer thickness, and the surface topography which depend on the etching conditions are the most important morphological parameters of PS layer<sup>15</sup>.

The porosity of mesoPS and macroPS was determined by a gravimetric method using the following equation<sup>19</sup>:

$$P = \frac{m_1 - m_2}{m_1 - m_3} \quad \dots (5)$$

where,  $m_1$ ,  $m_2$ ,  $m_3$  are the Si wafer weight before the process of etching, after the process of etching and after removal of PS layer in a solution of NaOH, respectively. It is found that the porosity of the mesoPS and macroPS samples has been estimated as 54% and 77%, respectively. Figure 2(a,b,c) shows the surface morphology of mesoPS layer at different magnifications and the cross-sectional FE-SEM image of the sample. The structure of mesoPS is a pore look like, spherical and irregular in shape, and the pores are randomly distributed on the surface. The statistical distribution of the pore sizes shows that the pores are in the range of (3–39) nm, and the peak of the pore size distribution is about 9 nm, as shown in Fig. 2(d). The magnified image of Fig. 2(b) illustrates that the micrometer size pores are present on the surface, therefore big enough AgNPs can form on the walls of the micropores, at the same time the pores aren't blocked by these nanoparticles and this leads to

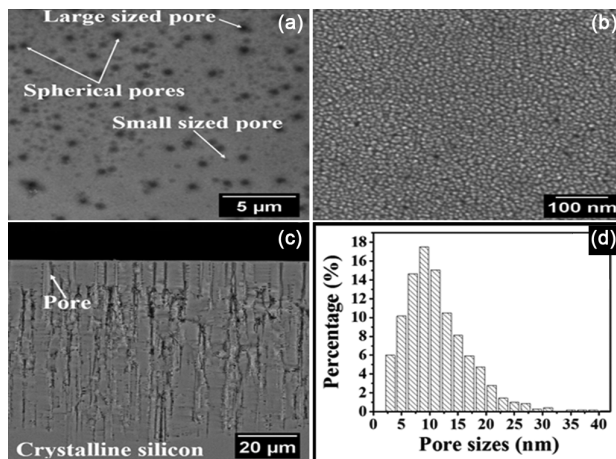


Fig. 2 — (a,b) FE-SEM images of mesoPS surface at scale bars of 5  $\mu\text{m}$  and 100 nm, respectively, (c) cross-sectional FE-SEM image of mesoPS sample and (d) the statistical distribution of pore sizes for the sample.

increase the effective surface of the sample<sup>3</sup>. As shown in the cross-sectional FE-SEM image of the mesoPS layer (Fig. 2(c)), the mesoPS layer thickness is about 77.58  $\mu\text{m}$ , and this means that the vertical deep pores extend from the surface into the Si crystal.

Figure 3(a,b) depicts the FE-SEM images of the macroPS sample. From this image, it's clear that the porous structure has a pore-like structure with pore sizes ranging from 0.5 to 5.5  $\mu\text{m}$ , and the peak of the pore size distribution is about 2.5  $\mu\text{m}$ , as manifested in Fig. 3(d). The dark spots regions on the images are attributed to the pores formed, whereas the white area corresponds to the remaining Si. The images reveal that some pores are overlapping, and the pores are randomly distributed on the porous surface (Fig. 3(a,b)). As shown in the cross-sectional FE-SEM image of the porous layer (Fig. 3(c)), the macroPS layer thickness is about 2.8  $\mu\text{m}$ , and it's easy to distinguish that the pore diameter changes gradually from the surface to the bulk.

This behavior is due to the fact that only the surface layers under illumination create the electron-hole pairs, therefore the etching rate will progressively reduce with the depth from the highest to the lowest layers yielding cone-like pores in PS structures<sup>20</sup>. This means that the nanocrystal at the PS/c-Si interface will become larger than the particles at the top of the nanostructure, so the layer seems as a double porous layer with a microPS on top of a macroPS, this behavior is confirmed by the PL spectrum, as shown in Fig. 4(b) later.

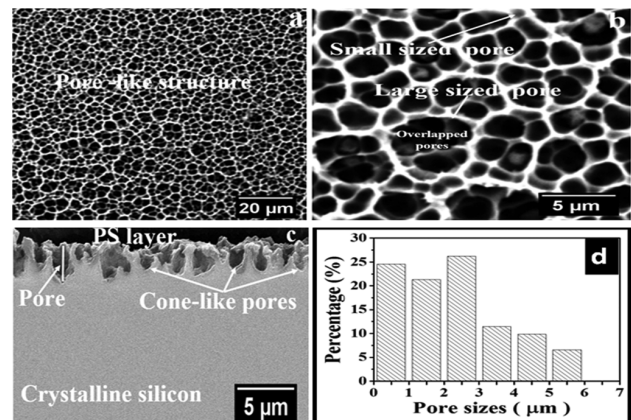


Fig. 3 — (a,b) FE-SEM images of macroPS surface at scale bars of 20  $\mu\text{m}$  and 5  $\mu\text{m}$ , respectively, (c) cross-sectional FE-SEM image of macroPS sample and (d) the statistical distribution of pore sizes for the sample.

### 3.2 PL properties of PS layer

PL spectra of PS are strongly dependent on the surface morphology of the porous layer<sup>15</sup>. Figure 4(a,b) shows the room temperature PL spectra of the mesoPS and macroPS samples, respectively. The PL spectrum of mesoPS sample depicts a single peak emission at 655.94 nm which corresponds to the energy gap of 1.89 eV, while the PL spectrum of macroPS has two peaks at 525.96 nm and 640.86 nm which correspond to the energy gaps of 2.36 eV and 1.94 eV, respectively. The appearance of the double peaks of PL is associated with the spatial size distribution of the nanocrystallites in macroPS sample as said before, the nanocrystal at the PS/c-Si interface is larger than the nanocrystal at the top of the PS structure, i.e., founding two PS layers on the porous structure. So, on exciting the macroPS structure, the peak at about 640.86 nm is due to the larger nanocrystals, and the peak at 525.96 nm is owing to the smaller nanocrystals. A small broadening and a large broadening of PL peak can be observed in Fig. 4(a,b), respectively. This is attributed to the distribution of nanosize particles since if it increases, the broadening of PL peak will increase and vice versa.

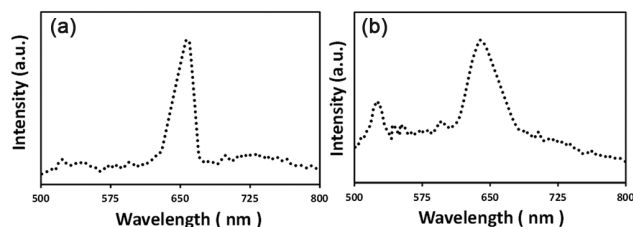


Fig. 4 — (a,b) PL spectra of mesoPS and macroPS

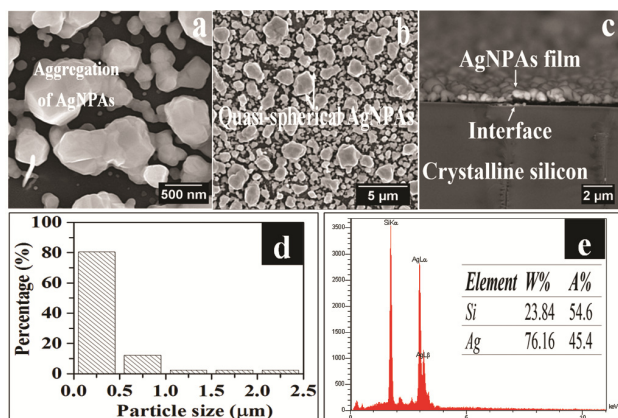


Fig. 5 — (a,b) FE-SEM images of AgNPs/mesoPS surface with scale bars of 500 nm and 5  $\mu\text{m}$ , respectively, (c) cross-sectional FE-SEM image, (d) the statistical distribution for the sizes of the AgNPs deposited on mesoPS and (e) EDX analysis of the sample. The inserted table of Fig. 5(e) displays the percentage of each component on the sample surface.

### 3.3 Morphological properties of AgNPs / PS

The immersion process of mesoPS and macroPS in  $\text{AgNO}_3$  solution is an effective way to form the AgNPs inside and outside the individual pores in the porous structure through the reduction process of Ag ions with the Si-H bonds<sup>3</sup>. The density, the size and the arrangement of the AgNPs depend on the morphology of the underlying substrate<sup>21</sup>. For mesoPS, the surface morphology is illustrated in Fig. 5(a,b,c). From this figure, it's clear that the AgNPs are located outside the pores in the porous structure. Because of the very small size of the pores in the mesoPS layer, the AgNPs couldn't enter inside the pores; therefore they aggregated on the surface of the mesoPS. This means that the mesoPS morphology (spongiform) supplied a high density of suitable nucleation sites for the AgNPs growth. This result is in a good agreement with that suggested by Giorgis *et al.*<sup>2</sup>. They have prepared AgNPs with densely close-packed on the mesoPS surface. The statistical distribution for the resulting sizes of AgNPs is presented in Fig. 5(d), and as shown from this figure, the Ag was deposited with the dispersion in size of particles ranging from 0.25  $\mu\text{m}$  to 2.25  $\mu\text{m}$ , and the peak of the AgNPs is about 0.25  $\mu\text{m}$ .

For macroPS layer, the surface morphology is demonstrated in Fig. 6(a,b,c). From this figure, it's easy to distinguish that the AgNPs are located inside the individual pores, and the AgNPs growth follows the pore morphology since they are uniformly distributed on the surface.

Figure 6(c) shows that AgNPs decorate the inner of the pores, and the pores are completely filled with AgNPs. Furthermore, Fig. 6(b) views that the separated silver nanoaggregates are formed (islands of AgNPs). This can be attributed to that the increase in the porosity leads to sharpen the surface roughness and so to increase the numbers of dangling Si bonds, which become passivated with hydrogen<sup>16</sup> (H), since the number of Si-H bonds plays a very important role in the process of Ag ions reduction<sup>3</sup>. The statistical distribution (Fig. 6(d)) for the sizes of AgNPs reveals that the Ag is deposited with the dispersion in size of particles ranging from 0.1  $\mu\text{m}$  to 1.5  $\mu\text{m}$ , and the peak of the particle sizes is about 0.1  $\mu\text{m}$ .

EDX was used to investigate the change in the surface composition of PS due to the coating by AgNPs. Figure 5(e) displays the existence of Ag and Si elements on the AgNPs/mesoPS sample, while Fig. 6(e) shows the existence of Si, Ag and oxygen

elements on the AgNPs/macroPS sample. The existence of Si element is attributed to the Si substrate, and the existence of oxygen element on the AgNPs/macroPS sample signifies the oxidation of Si.

**3.4 XRD analysis**

The XRD patterns of the mesoPS, macroPS, AgNPs/mesoPS and AgNPs/macroPS, respectively,

are illustrated in Fig. 7(a,b,c,d) which shows that for all the PS samples one diffraction peak appeared at  $2\theta$  about of  $33.26^\circ$  which is assigned to the (100) plane of Si according to the standards (JCPDS). Figure 7(c,d) exhibits that two peaks appeared at  $2\theta$  about of  $38.4^\circ$  and  $44.55^\circ$  for the AgNPs/mesoPS and at  $2\theta$  about of  $38.28^\circ$  and  $44.47^\circ$  for the AgNPs/macroPS which are assigned to the (111)

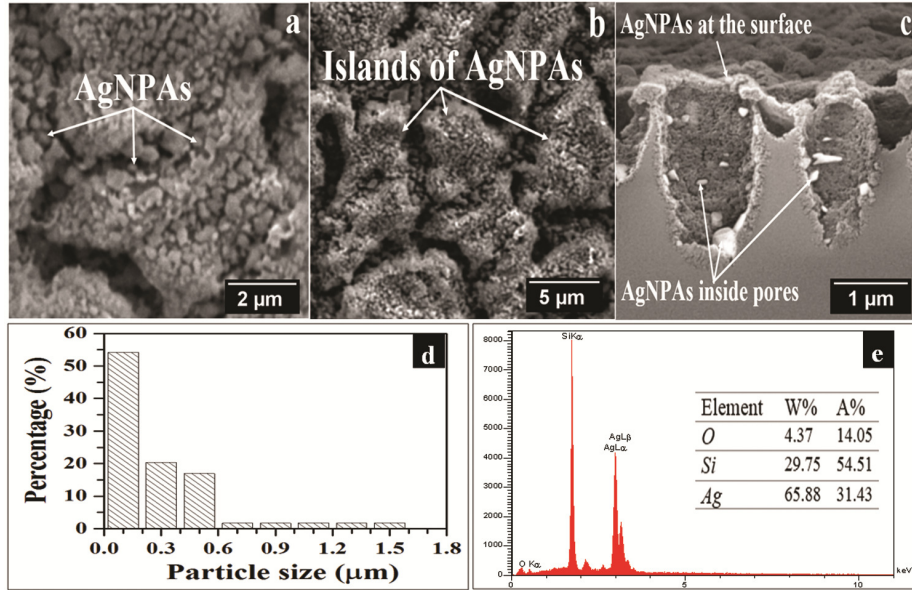


Fig. 6 — (a, b) FE–SEM images of AgNPs/macroPS surface with scale bars of 2 μm and 5 μm, respectively, (c) cross–sectional FE–SEM image, (d) the distribution diagrams for the sizes of the AgNPs deposited on macroPS and (e) EDX analysis of the sample. The inserted table in (e) displays the percentage of the each component on the sample surface.

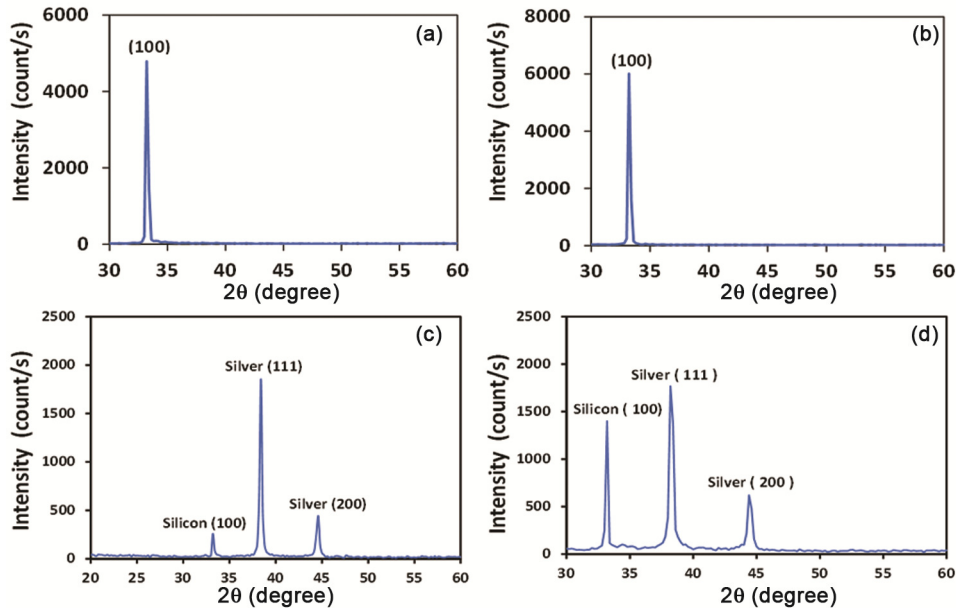


Fig. 7 — XRD patterns of the (a) mesoPS, (b) macroPS, (c) AgNPs/mesoPS and (d) AgNPs/macroPS.

and (200) crystal planes of Ag, respectively. They are compared with JCPDS, all the reflections match to pure Ag element with face centered cubic symmetry (FCC). This result is in agreement with the results reported in the literature<sup>13,22</sup>. The intensity of peaks demonstrated the great degree of the AgNPs crystallinity. The diffraction of the peaks is obviously broadened as compared with bulk Ag, denoting the formation of AgNPs. It is very clear that the Ag deposition process leads to the decreasing in the intensity of the reflection from the (100) plane of Si, this is attributed to the covering of the sample surfaces by the AgNPs.

The structural parameters for AgNPs are calculated from XRD results. The data are tabulated in the Table 1. The sizes of the AgNPs ( $D_p$ ) are calculated by using Scherrer's formula<sup>23</sup> as follows:

$$D_p = \frac{0.9\lambda}{\beta \cos\theta} \quad \dots (6)$$

where,  $\beta$  is the full width at half maximum (radians),  $\lambda$  is the wavelength in nm of employed radiation,  $\theta$  is the Bragg diffraction angle in degree and (0.9) is the shape factor value.

Specific surface area ( $S$ ) is the property of the material. The AgNPs have attracted much attention because they have a high specific surface area which can be calculated by using the following equation<sup>24</sup>:

$$S = \frac{6000}{D_p \rho} \quad \dots (7)$$

where,  $\rho$  is the density of Ag 10.5 g/cm<sup>3</sup>, since it is found for (111) direction that the size and specific

Table 1 — Structural parameters of AgNPs.

Structural parameters of silver nanocrystallite		AgNPs/mesoPS	AgNPs/macroPS
		<i>hcl</i> (JCPDS) file No. 03-0921	<i>hcl</i> (JCPDS) file No. 03-0921
		(111) silver	(111) silver
2 $\theta$ (degree)	Experimental	38.4	38.28
	(JCPDS)	38.1	38.1
$d$ -space (nm)	Experimental	0.234	0.235
	(JCPDS)	0.2359	0.2359
$a$ (nm)	Experimental	0.4052	0.407
	(JCPDS)	0.4074	0.4074
$\beta$ (radians)		0.0085	0.009
$D_p$ (nm)		17.26	16.3
$S$ (m <sup>2</sup> /g)		33.14	35.09

surface area of AgNPs are 17.26 nm and 33.41 m<sup>2</sup>/g, respectively, for sample Ag/mesoPS and 16.3 nm and 35.09 m<sup>2</sup>/g for sample AgNPA/macroPS, respectively.

Since the FE-SEM images indicate the aggregated particle sizes, the grain sizes of the AgNPs/mesoPS and AgNPs/macroPS samples which were determined from the XRD data are smaller than that obtained from the FE-SEM images. The bigger nanoparticles can be attributed to the tendency of the AgNPs to conglomerate due to their great surface energy and great surface tension of the ultrafine nanoparticles<sup>25</sup>.

### 3.5 SERS of AgNPs/mesoPS and AgNPs/macroPS

Figure 8 shows the Raman spectra of R6G adsorbed on (a) fresh mesoPS substrate and (b) fresh macroPS substrate at 10<sup>-4</sup> M concentration of dye solution. The substrates of fresh PS exhibit a very low Raman signal.

Figure 9 manifests the SERS spectra of R6G dye excited at 532 nm at R6G dye solution concentration of 10<sup>-6</sup> M adsorbed on AgNPs/mesoPS and AgNPs/macroPS substrates. The peaks appearing at 637, 708, 945, 1215, 1294, 1371, 1530 and 1660 cm<sup>-1</sup> are the characteristic Raman lines of R6G molecules. The SERS spectra of R6G on AgNPs/mesoPS and AgNPs/macroPS substrates can be compared with other works<sup>3,26</sup>.

The  $EF$  is calculated using the following equation<sup>27</sup>:

$$EF = \frac{I_{SERS}/C_{SERS}}{I_{RS}/C_{RS}} \quad \dots (8)$$

where,  $I_{SERS}$  is the SERS signal with a certain concentration of  $C_{SERS}$ , and  $I_{RS}$  is the Raman signal under non-SERS conditions with a concentration of  $C_{RS}$ . In this study,  $I_{RS}$  and  $I_{SERS}$  were determined using the highest peak of ~1660 cm<sup>-1</sup> as a reference peak on AgNPs/mesoPS and AgNPs/macroPS. It is found that the value of the  $EF$  achieved by using AgNPs/macroPS substrate is two orders of magnitude higher than that of AgNPs/mesoPS substrate of about (1.8×10<sup>6</sup>) and (3.2×10<sup>4</sup>), respectively.

This can be attributed to the difference between the morphology of the AgNPs deposited on macroPS and mesoPS, since it is found that AgNPs deposited on macroPS are more condensed and the dispersion in size of particles deposited on macroPS is less than that of particles deposited on mesoPS. Therefore, the interspacing boosted much stronger SERS "hotspots".

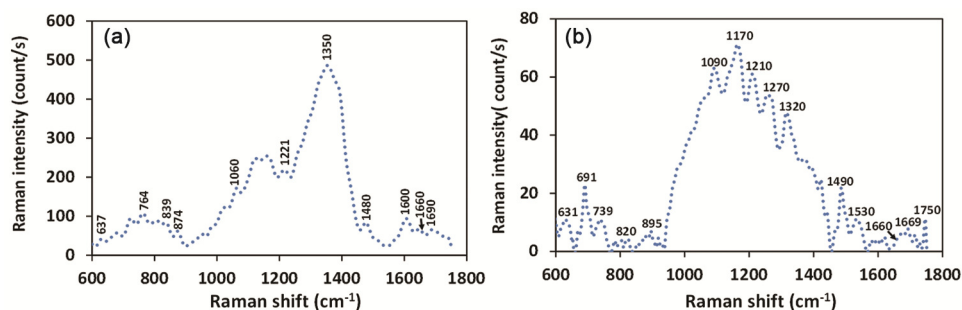


Fig. 8 — Raman spectra of R6G dye at concentration of  $10^{-4}$  M adsorbed on (a) mesoPS and (b) macroPS substrates.

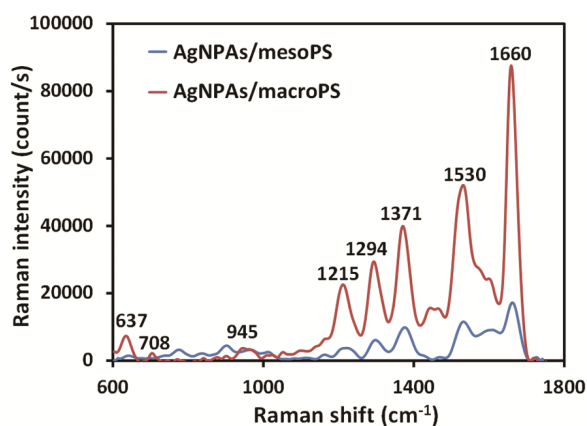


Fig. 9 — SERS spectra of R6G dye adsorbed on AgNPs/mesoPS and on AgNPs/macroPS at fixed dye solution concentration of  $10^{-6}$  M and fixed immersion time of 16 min.

#### 4 Conclusions

In summary, AgNPs/mesoPS and AgNPs/macroPS were prepared by immersion process of PS samples in  $\text{AgNO}_3$  solution. The sizes and morphology of AgNPs depend on the underlying substrate morphology. AgNPs were deposited on the two kinds of substrates, namely mesoPS and macroPS, in the case of using mesoPS substrate, the AgNPs couldn't enter inside the pores, therefore they aggregated on the surface of the mesoPS, while in the case of using macroPS substrate, the AgNPs decorated the inner of the pores, the pores are completely filled with them, and the separated Ag nanoaggregates are formed on the macroPS surface. Thus, AgNPs can be prepared with specific sizes by controlling the surface morphology of PS substrate. Highest Raman intensity is obtained for AgNPs/macroPS substrate comparing with AgNPs/mesoPS by two orders of magnitude. The SERS efficiency of substrate is strictly related to the morphology of PS layer at fixed immersion plating parameters.

#### Acknowledgment

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